

Tantalum Carbide (TaC) Sputtering Targets

Material Type	Tantalum Carbide	Theoretical Density (g/cc)	13.9
Symbol	TaC	Z Ratio	**1.00
Melting Point (°C)	3,880	Sputter	RF
Purity:	99.99%, 99.95%	Max Power Density	27
		(Watts/Square Inch)	
		Type of Bond	Indium